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SGH40N60UF 600 V PT IGBT

General Description

Fairchild's UF series IGBTs provide low conduction and switching losses. UF series is designed for the applications such as general inverter and PFC where high speed switching is required feature.

Features

- High Speed Switching
- Low Saturation Voltage: $V_{CE(sat)} = 2.1 \text{ V} @ I_C = 20 \text{ A}$
- High Input Impedance

Application

· General Inverter, PFC







Absolute Maximum Ratings $T_C = 25$ °C unless otherwise noted

| Symbol | Description | | Ratings | Unit |
|---------------------|---|--------------------------|-------------|------|
| V _{CES} | Collector-Emitter Voltage | | 600 | V |
| V _{GES} | Gate-Emitter Voltage | | ± 20 | V |
| | Collector Current | @ $T_C = 25^{\circ}C$ | 40 | A |
| IC | Collector Current | @ T _C = 100°C | 20 | A |
| I _{CM (1)} | Pulsed Collector Current | | 160 | A |
| P _D | Maximum Power Dissipation | @ T _C = 25°C | 160 | W |
| | Maximum Power Dissipation | @ T _C = 100°C | 64 | W |
| TJ | Operating Junction Temperature | | -55 to +150 | °C |
| T _{stg} | Storage Temperature Range | | -55 to +150 | °C |
| TL | Maximum Lead Temp. for Soldering Purposes, 1/8" from Case for 5 Seconds | | 300 | °C |

Notes

(1) Repetitive rating : Pulse width limited by max. junction temperature

Thermal Characteristics

| Symbol | Parameter | Тур. | Max. | Unit |
|-----------------|---|------|------|------|
| $R_{\theta JC}$ | Thermal Resistance, Junction-to-Case | | 0.77 | °C/W |
| $R_{\theta JA}$ | Thermal Resistance, Junction-to-Ambient | | 40 | °C/W |

Electrical Characteristics of the IGBT $T_C = 25^{\circ}C$ unless otherwise noted

| Symbol | Parameter | Test Conditions | Min. | Тур. | Max. | Unit |
|---|--|--|-----------|------------|------------|----------|
| Off Cha | racteristics | | | | | |
| BV _{CES} | Collector-Emitter Breakdown Voltage | $V_{GE} = 0 \text{ V, } I_{C} = 250 \text{ uA}$ | 600 | | | V |
| ΔB _{VCES} / ΔT _J | Temperature Coefficient of Breakdown Voltage | V _{GE} = 0 V, I _C = 1 mA | | 0.6 | | V/°C |
| I _{CES} | Collector Cut-Off Current | V _{CE} = V _{CES} , V _{GE} = 0 V | | | 250 | uA |
| I_{GES} | G-E Leakage Current | $V_{GE} = V_{GES}, V_{CE} = 0 V$ | | | ± 100 | nΑ |
| On Chai | racteristics | | | | | |
| V _{GE(th)} | G-E Threshold Voltage | $I_C = 20 \text{ mA}, V_{CE} = V_{GE}$ | 3.5 | 4.5 | 6.5 | V |
| | Collector to Emitter | $I_C = 20 \text{ A}, V_{GE} = 15 \text{ V}$ | | 2.1 | 2.6 | V |
| V _{CE(sat)} | Saturation Voltage | I _C = 40 A, V _{GE} = 15 V | | 2.6 | | V |
| Dynami | c Characteristics | | | | | |
| C _{ies} | Input Capacitance | V 00 V V 0 V | / | 1430 | | pF |
| C _{oes} | Output Capacitance | $V_{CE} = 30 \text{ V}, V_{GE} = 0 \text{ V},$ f = 1 MHz | | 170 | | рF |
| C _{res} | Reverse Transfer Capacitance | T = T IVITIZ | | 50 | | pF |
| | ng Characteristics | | | | 1 | |
| t _{d(on)} | Turn-On Delay Time | - | | 15 | | ns |
| t _r | Rise Time | | | 30 | | ns |
| t _{d(off)} | Turn-Off Delay Time | $V_{CC} = 300 \text{ V}, I_C = 20 \text{ A},$ | | 65 | 130 | ns |
| t _f | Fall Time | $R_G = 10 \Omega$, $V_{GE} = 15 V$, | | 50 | 150 | ns |
| E _{on} | Turn-On Switching Loss | Inductive Load, T _C = 25°C | | 160 | | uJ |
| E _{off} | Turn-Off Switching Loss | - | | 200 | | uJ |
| E _{ts} | Total Switching Loss | | | 360 | 600 | uJ |
| t _{d(on)} | Turn-On Delay Time Rise Time | - | | 30 37 | | ns |
| t _r | | ., | | | | ns |
| t _{d(off)} | Turn-Off Delay Time Fall Time | $V_{CC} = 300 \text{ V, } I_{C} = 20 \text{ A,}$ $R_{G} = 10 \Omega, V_{GE} = 15 \text{ V,}$ Inductive Load, $T_{C} = 125^{\circ}\text{C}$ | | 110 144 | 200 250 | ns |
| t _f ⊏ | Turn-On Switching Loss | | | 310 | 230 | ns uJ |
| E _{on} E _{off} | Turn-Off Switching Loss | | | 430 | | uJ |
| ∟ _{off} E _{ts} | Total Switching Loss | | | 740 | 1200 | uJ |
| Q _a | Total Gate Charge | | | 97 | 150 | nC |
| Q_ge | Gate-Emitter Charge | $V_{CE} = 300 \text{ V}, I_{C} = 20 \text{ A},$ | | 20 | 30 | nC |
| Q_gc | Gate-Collector Charge | V _{GE} = 15 V | | 25 | 40 | nC |
| L _e | Internal Emitter Inductance | Measured 5mm from PKG | | 14 | | nH |
| - e | miomai Emilio maddano | Wicadarda Sililii Ilolii I NO | | 17 | | - 11 |

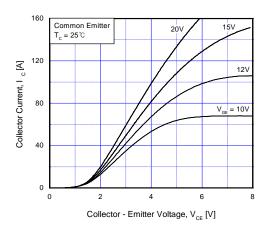
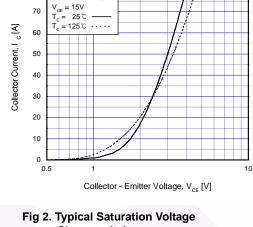


Fig 1. Typical Output Characteristics



80

Common Emitter

Characteristics

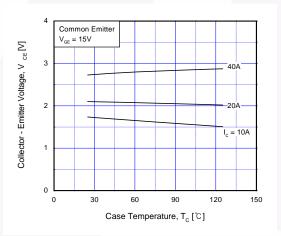


Fig 3. Saturation Voltage vs. Case **Temperature at Variant Current Level**

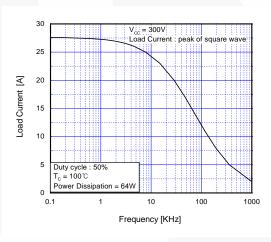


Fig 4. Load Current vs. Frequency

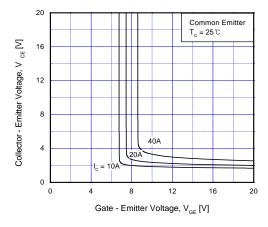


Fig 5. Saturation Voltage vs. V_{GE}

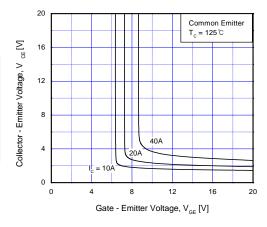


Fig 6. Saturation Voltage vs. V_{GE}

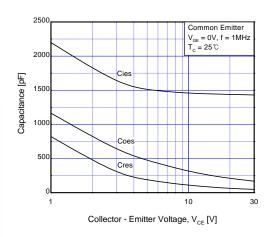


Fig 7. Capacitance Characteristics

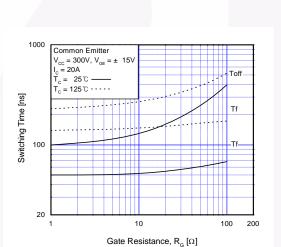


Fig 9. Turn-Off Characteristics vs.
Gate Resistance

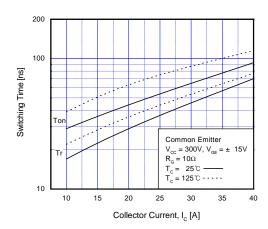


Fig 11. Turn-On Characteristics vs. Collector Current

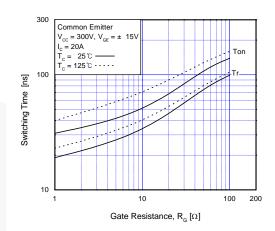


Fig 8. Turn-On Characteristics vs.
Gate Resistance

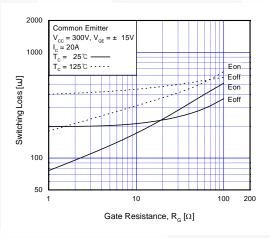


Fig 10. Switching Loss vs. Gate Resistance

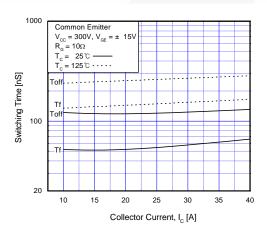


Fig 12. Turn-Off Characteristics vs. Collector Current

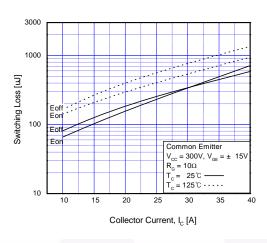


Fig 13. Switching Loss vs. Collector Current

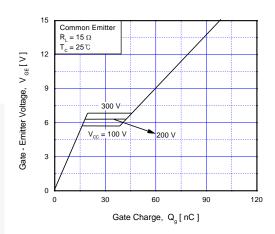


Fig 14. Gate Charge Characteristics

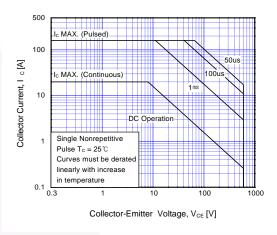


Fig 15. SOA Characteristics

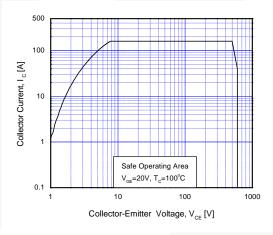


Fig 16. Turn-Off SOA Characteristics

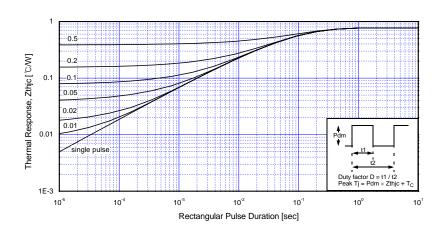


Fig 17. Transient Thermal Impedance of IGBT

Mechanical Dimensions

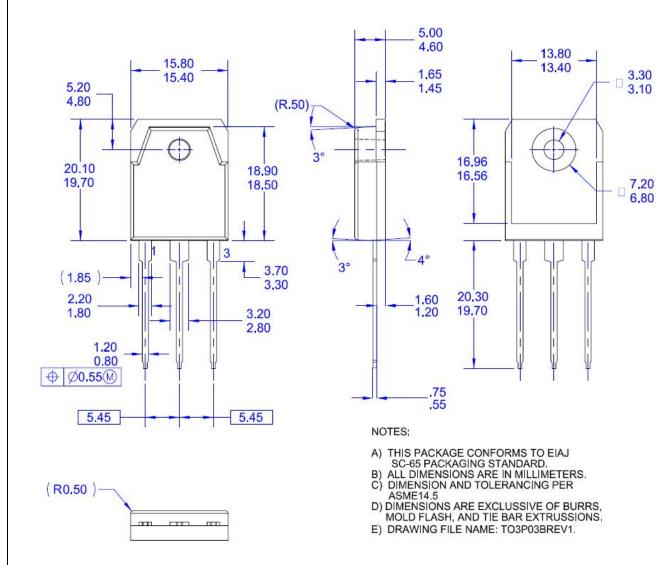


Figure 18. TO-3P 3L - 3LD, T03, PLASTIC, EIAJ SC-65

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